High mobility transport in isotopically-enriched ¹²C and ¹³C exfoliated graphene

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Graphene quantum dots are promising candidates for qubits due to weak spin-orbit and hyperfine interactions. The hyperfine interaction, controllable via isotopic purification, could be the key to further improving the coherence. Here, we use isotopically enriched graphite crystals of both ¹²C and ¹³C grown by high-pressure-high-temperature method to exfoliate graphene layers. We fabricated Hall bar devices and performed quantum transport measurements, revealing mobilities exceeding $10^5 \text{cm}^2/Vs$ and a long mean free path of microns, which are as high as natural graphene. Shubnikov-de Haas oscillations, quantum Hall effect up to the filling factor of one, and Brown-Zak oscillations due to the alignment of hBN and graphene are observed thanks to the high mobility. These results constitute a material platform for physics and engineering of isotopically-enriched graphene qubits.

I. INTRODUCTION

Graphene quantum dots are among the most promising candidates as platforms for spin qubits[1-3] thanks to the weak spin-orbit coupling and hyperfine interactions. Understanding the hyperfine interaction is a strategy to improve the qubit coherence in several systems such as GaAs[4–7] and Si-based systems [8–10]. The hyperfine interaction has also been investigated in ¹³Cenriched carbon nanotube quantum dots [11] and it was theoretically proposed that graphene quantum dots could benefit from isototpe purificiaction.[1, 12–14], modulating the ratio of ${}^{12}C$ (nuclear spin 0) and ${}^{13}C$ (nuclear spin 1/2) (see Appendix A). Comparing the results of ${}^{12}C$ and ¹³C-enrichment would enable the direct investigation of the effect of hyperfine interaction. While isotopicallyenriched graphene has been realized, they have been made by the chemical vapor deposition (CVD) method [15, 16], whose electronic quality is usually not as high as for exfoliated samples and thus challenging for qubit fabrication.

In this work, we investigate high-quality exfoliated graphene devices out of 12 C-enriched (99.7%) and 13 C-enriched (91.4%) graphites. We synthesize enriched graphite by the high-pressure-high-temperature method [17, 18]. We then establish a recipe to exfoliate the layered crystals to obtain monolayer and bilayer graphene. The isotope effect is characterized by mass spectroscopy and Raman spectroscopy, showing a clear difference between 12 C and 13 C graphene. After confirming the enrichment, we fabricate a Hall bar device from each kind of graphite and perform quantum transport measurements.

For both graphene samples, high mobility ($\mu \ge 1 \times 10^5$ cm²/Vs) and long mean free path ($l_{\rm mfp} \ge 1 \mu$ m) are demonstrated. These values demonstrate that the electronic quality of graphene remains as high as natural graphene after isotopic enrichment. We also observe the Shubnikov-de Haas oscillations, quantum Hall effect, and Brown-Zak oscillations, which confirm the quality of the sample. This result forms the basis for building isotopically-enriched graphene qubits and investigating the role of hyperfine interactions.

II. CHARACTERIZATION RESULTS

A. Enriched graphite and exfoliation

Figure 1(a) shows the optical picture of the crystal of ¹²C-enriched and ¹³C-enriched graphite. Hereafter, we call them ${}^{12}C$ graphite/graphene and ${}^{13}C$ graphite/graphene for convenience. Isotopically enriched graphite crystals are obtained using Co-Ti solvents by a temperature difference method under high pressure. This method modifies the high-pressure synthesis conditions of diamond single crystals in the graphite stability region of 3 GPa and 1600 °C for 20 hrs [19]. The carbon source material is dissolved in the molten solvent under high pressure and high temperature and precipitated as a graphite crystal. The source materials are ¹²C-enriched diamond crystals prepared by CVD using ¹²C-enriched methane gas (Tomei-diamond Co Ltd) and commercially available ¹³C-enriched graphite. After high-pressure synthesis, the metallic solvents are removed with hot aqua regia, and the graphite crystals are purified with pure water.

Note that the crystal size ($\sim 5 \text{ mm}$) is relatively small compared to the natural graphite crystals, which can be

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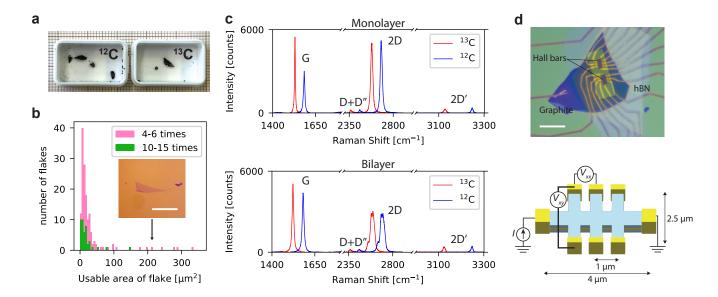


FIG. 1. (a) Optical picture of ¹²C and ¹³C graphite crystals. The minimum grid size in the background is 1 mm. (b) Histogram of ¹²C graphene flake size. Inset shows a picture of the example bilayer flake. The scale bar is 50 μ m. (c) Raman spectrum of ¹²C and ¹³C graphene. Top: Monolayer graphene. Bottom: Bilayer graphene. (d) Top panel: Optical picture of the fabricated Hall bar. The scale bar is 10 um. Bottom panel: Schematic of the fabricated Hall bar. Source, drain, and voltage terminals are shown together with the geometric measurements.

up to of the order of cm. The relative isotope ratio found in the crystals is determined using inductively coupled plasma time-of-flight mass spectrometry (ICP-TOFMS). The ICP-TOFMS (icp-TOF2R, TOFWERK AG, Thun, Switzerland) is operated in low-mass mode and was coupled to an ArF excimer laser (193 nm, GeoLas C, Lambda Physik, Göttingen), equipped with a low dispersion ablation cell for minimally invasive sampling of the small crystals. The ratios of isotopes are determined for natural graphite, ¹²C graphite, and ¹³C graphite. The results of the natural graphite are used to calibrate the ratio for the other samples, assuming the natural abundance of ${}^{12}C:{}^{13}C = 98.9$: 1.1. The result of the mass spectroscopy yields ${}^{12}C:{}^{13}C = 99.7: 0.3$ for the ${}^{12}C$ sample and 8.6: 91.4 for the ¹³C sample, confirming the effect of enrichment. The relative concentrations of the isotopes determined by mass spectroscopy have a relatively large error because of the small amount of the sample available.

In spite of the relatively small size of the graphite crystals, exfoliation is possible for both ¹²C and ¹³C. We perform exfoliation by using the standard scotch tape method, where we deposit graphite onto the scotch tape and fold and peel apart the tape a certain number of times before the flakes are transferred onto a Si/SiO2 substrate. We compare exfoliation for folding and peeling apart the tape 4-6 times with 10-15 times. We analyze the chips under a microscope and record the size of the flakes. The statistics of the flake size (mono-, bi-, and trilayer ¹²C graphene) is shown in Figure 1(b), together with an image of an example of a large bilayer flake. It turns out that after 4-6 times of exfoliation, it is possible to obtain 50 μ m scale graphene flakes of mono, bi, and tri

layers. The same result is obtained for the ${}^{13}C$ graphene. These results demonstrate that the enriched ${}^{12}C$ and ${}^{13}C$ exfoliation is possible and that the flakes are available for fabricating devices.

B. Raman spectroscopy

The exfoliated graphene is further characterized by Raman spectroscopy (Horiba LabRAM HR Evolution UV-VIS-NIR). The laser energy and wavelength are 1 mW and 532 nm, respectively. We choose a flake larger than 10 µm and perform a Raman spectrum measurement by changing the laser position. The data shown in Fig 1(c)is from the part of the graphene that is a few µm inside from the edge of the flake. The measurements are done on mono and bilayer flakes. As shown in Fig. 1(c), both ¹²C and ¹³C graphene show prominent G (~1520-1580 cm⁻¹), D+D^{''} (~2360-2490 cm⁻¹), 2D (~2540-2710 cm^{-1}), and 2D' (~3120-3250 cm⁻¹) peaks. The numbers in the parentheses are typical ranges of the observed peak wavenumbers. We see a clear peak wavenumber shift between ${}^{12}C$ and ${}^{13}C$. These differences are one of the most prominent signatures of the isotope effect because the nuclear mass difference results in a phonon frequency and Raman shift difference. We do not observe a shift between ${}^{12}C$ and natural graphene within the experimental resolution. After subtracting a linear background from the data, we fit all the peaks with Lorentzian functions. The fit parameters are in the table in Appendix B.

The obtained parameters are consistent with the ones

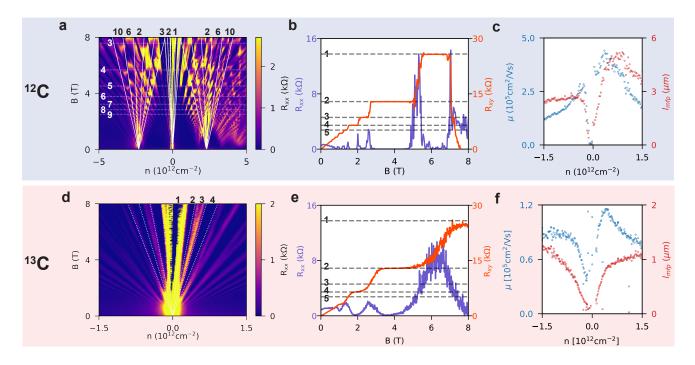


FIG. 2. Quantum transport measurement of 12 C (a,b,c) and 13 C (d,e,f) bilayer graphene. (a,d) R_{xx} as a function of magnetic field *B* and carrier density *n*. White dotted tilted lines fit the Shubnikov-de Haas oscillations with filling factors shown in the Figure. White dotted horizontal lines show the position at which the Brown-Zak oscillations appear. (b,e) Example traces of the quantum Hall effect at $n = 1.13 \times 10^{11}$ (12 C) and $n = 1.9 \times 10^{11}$ (13 C). (c,f) Carrier density *n* dependence of the mobility μ and the mean free path l_{mfp} estimated from the low magnetic field data.

reported in exfoliated natural graphene and isotopically enriched CVD graphene [20-24]. The measured wavenumber of the G peak, ω_G , for ¹²C or natural graphene reported in Refs. [20-24] are between $-2 \,\mathrm{cm}^{-1}$ and $10 \,\mathrm{cm^{-1}}$ of our measured values for $^{12}\mathrm{C}$ graphene (for mono- and bilayer). The ω_G for ¹³C graphene reported in [22, 24] is in the range of -5 cm^{-1} to 8 cm^{-1} of the values we measure for mono- or bilayer. Comparing the wavenumber of the 2D peak, ω_{2D} , to literature values, it turns out that the values reported are generally slightly higher (up to 1.5 %) than the values we measure. For the monolayer ¹²C graphene ω_{2D} , we find that our measurement aligns very well (within $1 \,\mathrm{cm}^{-1}$) with the natural graphene measurement in [20]. However, the measurements in Refs. [22-24] find values $15-35 \,\mathrm{cm}^{-1}$ higher than what we measure for ¹²C monolayer graphene as well as for ¹³C monolayer graphene. Looking at the bilayer measurements for ω_{2D} peaks [20], we find two peaks that are 2 cm^{-1} and 3 cm^{-1} apart. For $\omega_{2D'}$ [25] reports 3250 cm^{-1} for ¹²C graphene and 3130 cm^{-1} for ¹³C graphene. These values are consistent with what we measure.

We also estimate the isotopic concentration of ¹³C graphene from the Raman shift using the relation $\omega = \omega_{12C}\sqrt{\frac{m}{m+x\Delta m}}$ [26]. Here, ω_{12C} is the Raman shift of pure ¹²C graphene, *m* is atomic mass of ¹²C, *x* is the concentration of ¹³C, and Δm the atomic mass differ-

ence of ¹²C and ¹³C. For ¹³C graphene, we obtain a ¹³C enrichment x = 92.9% using the 2D and 2D' peaks and x = 86.2% using the G peak. Since the G peak is sensitive to the distortion and carrier density [27], it can be affected by unintentional doping due to the charged impurity in the silicon substrate, making the peak shift. The estimation from 2D and 2D' peaks is closer to the value obtained by the mass spectroscopy with a slight overestimation (±1.5%). At around 93% of ¹³C, the deviation of Raman shifts by one cm⁻¹ modulates the concentration estimation by ~ 1.7%. Therefore, considering the resolution of the measurement, the estimation from the 2D and 2D' peaks is consistent with the one from the mass spectroscopy.

C. Device fabrication

To characterize the transport quality of the isotopically enriched graphene, we fabricate Hall bars of 12 C and 13 C bilayer graphene as shown in Figure 1(d). A stack of hexagonal boron-nitride (top hBN)/bilayer graphene/hBN (bottom hBN)/graphite (back gate) is made by the poly-dimethylsiloxane/poly-carbonates dry transfer method. Electric contacts to the edge of the bilayer graphene are fabricated by etching the top hBN and depositing Cr/Au. After etching, a Hall bar is shaped by

reactive ion etching (CHF₃ and O_2). We measure the Hall bars in a dilution refrigerator with a base temperature of 55 mK. The bottom panel of Fig. 1(d) shows the schematic of the device. The two contacts at each sample end are used as source and drain electrodes, where we inject current from the source to the grounded drain. The longitudinal and transverse voltages $(V_x \text{ and } V_y)$ are measured between the two contacts along and across the sides. The spacing between source and drain, and between the voltage contacts is 4 µm and 1 µm, respectively. We use a lock-in amplifier (Stanford Research Systems SR830) connected to the source in series with a $100 \,\mathrm{M}\Omega$ resistance and apply an AC voltage of 1V, generating an AC current of 10 nA. We synchronize the lock-in amplifier driving the current I with the other two lock-in amplifiers. These lock-in amplifiers are then used to measure the resistances $(R_{xx} = \frac{dV_x}{dI} \text{ and } R_{xy} = \frac{dV_y}{dI} \text{ at zero bias current})$. We apply a DC voltage (Yokogawa 7651 Programmable DC Source) to the back gate (not shown in the schematic).

III. TRANSPORT MEASUREMENT

Figures 2(a) and (d) show the magnetic field B and the carrier density n dependence of the longitudinal resistance R_{xx} of ¹²C and ¹³C devices. The carrier density on the horizontal axis is estimated by measuring the classical Hall effect up to 100 mT and using the relation $R_{xy} = \frac{B}{n|e|}$. We also obtain consistent values from a parallel plate capacitor model ($n = C_{bg}V_{bg}$, where C_{bg} is the capacitance between the graphene and the back gate and V_{bg} is the back gate voltage) and Shubnikov-de Haas measurements ($R_{xx} \propto \cos(\frac{2\pi nh}{4eB})$).

For both samples, clear fan-like structures departing from the charge neutrality point n = 0 and expanding with magnetic field are seen, which is attributed to the Shubnikov-de Haas (SdH) oscillations. The oscillations appear already at around 1 T, testifying to our samples' high mobility. White dotted tilted lines show the fitting to the filling factor of 1, 2, and 3 at around n = 0 (for ${}^{12}C$ and ${}^{13}C$) and filling factor for 2, 6, and 10 at around $n = \pm 2.3 \times 10^{12}$ cm⁻² (for ${}^{12}C$ only). Additionally, in the ${}^{12}C$ sample, we see multiple Lan-

Additionally, in the ¹²C sample, we see multiple Landau fans appearing at densities of around 4.09, 3.29, 2.30, 1.78, -2.06, and -2.31 ×10¹² cm⁻². This is attributed to the additional Dirac points due to the unintended alignment between the graphene and one of the hBNs, forming a moiré superlattice [28]. This results in an energy spectrum for the charge carriers known as the Hofstadter butterfly and causes satellite Dirac peaks. Furthermore, at the intersections of the Landau fans, it predicts horizontal lines of peaks in R_{xx} called Brown-Zak oscillations [29, 30]. The horizontal lines in Fig. 2(a) indicate the position of $\phi/\phi_0 = 1/p$ with p an integer and $\phi_0 = h/e$ the flux quanta. As we discuss in Appendix C, the moiré unit cell size estimated from the Brown-Zak oscillations agrees with the one formed by graphene/hBN alignment. This observation is another piece of evidence for having a high-quality sample.

At a high magnetic field, we observe the quantum Hall effect, as shown in Figs. 2(b) and (e). For both samples, the integer quantum Hall effect is observed up to filling factor $\nu = 1$ with quantized plateaus of R_{xy} and dips of R_{xx} . The significant drop of R_{xy} in ¹²C beyond filling factor 1 ($B \ge 7$ T) is due to the Brown-Zak oscillations. We observe a similar drop whenever B crosses the horizontal lines indicated in Fig. 2(a).

We also estimate the mobility μ and mean free path $l_{\rm mfp}$ by applying the classical Drude model to $\rho_{xx} = \frac{W}{L}R_{xx}$ (W and L are the width and the length of the sample) and $\rho_{xy} = R_{xy}$ at a low magnetic field (≤ 100 mT). From the slope of the linear fit of R_{xy} up to 100 mT together with R_{xx} at 0 T, we determine μ and $l_{\rm mfp}$ using the equations $\mu = \frac{1}{\rho_{xx}(B=0)} \frac{d\rho_{xy}}{dB}$ and $l_{\rm mfp} = \frac{\hbar\sqrt{\pi n}}{|e|}\mu$. As seen in Figure 2(c) and (f), the mobility mostly ranges from 1×10^4 to 3×10^5 cm²/Vs. The mobility becomes zero around charge neutrality and forms a peak with increasing *n*. This behavior can be attributed to the difference in dominant scattering mechanisms (long-range Coulomb scattering at low density and short-range impurity scattering at high density) [31].

The mean free path $l_{\rm mfp}$ reaches up to $1-5\,\mu{\rm m}$ for both $^{12}{\rm C}$ and $^{13}{\rm C}$. This value is comparable to the one reported in natural graphene. Note that the spacing between the contacts is of the same order of magnitude as the estimated mean free path, meaning that the transport in the sample is in the ballistic regime. In this regime, the Drude model has limited validity, and the mobility and mean free path are lower bound estimates.

We further perform a quantum Hall effect breakdown measurement, applying a DC current up to 10 µA so that the quantum Hall effect (plateau in ρ_{xy} and zero in ρ_{xx}) is no longer observed. In GaAs 2DEG systems, a large hysteresis in the current sweep direction before and after the breakdown is observed typically for odd filling factors due to dynamic nuclear polarization (spin transfer from electrons to nuclei) [32, 33]. We do not observe any clear hysteresis within our measurement precision (data is not shown here). To observe the effect of hyperfine interaction, more sophisticated measurements such as resistivity-detected NMR [34–36] or actually building a quantum dot and performing a T_1 and T_2 coherence time measurement would be useful.

IV. CONCLUSION

In conclusion, we have presented high-mobility transport of exfoliated ¹²C and ¹³C graphene synthesized by the high-pressure-high-temperature technique. We identified distinct differences between ¹²C and ¹³C graphene by the mass and Raman spectroscopy. We also fabricated Hall bar devices and performed quantum transport measurements, revealing high mobility and a long mean free path. Shubnikov-de Haas, quantum Hall, and Brown-Zak effects up to the filling factor of one were observed thanks to the high mobility. These results pave the way for developing isotopically-enriched graphene qubits and investigating the role of hyperfine interactions in graphene quantum dots.

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Appendix A: Coherence time estimation

Following the steps of [1], we studied the effect of isotopic composition on the lifetime τ of coherent spin states (T_2) in graphene quantum dot qubits. While the different atomic masses of ¹²C and ¹³C may affect the spin-orbit coupling, it is believed that the hyperfine interaction limits the coherence time in graphene [1]. The limit on the coherence time) $\tau_{\rm hf}$ depends on the composition of the spinless ¹²C and the spin-1/2 ¹³C. It can be estimated from the hyperfine coupling strength $A_{\rm hf} = 0.38 \,\mu \rm eV$, the ¹³C concentration c_{13C} and the number of atom in a dot N using $\tau_{\rm hf} = \frac{\hbar}{A_{\rm hf}} \sqrt{N/c_{13C}}$.

Compared to natural graphene ($c_{13C} = 1.1\%$; $N = 10^4 : \tau_{\rm hf} \approx 10\,\mu\rm{s}$) the purification level of our ¹²C sample ($c_{13C} = 0.3\%$) would already increase the hyperfine coherence time by a factor of two. Further decreasing the ¹³C concentration (99.99% purified ¹²C), would increase the coherence time by another factor of five, to around $\tau_{\rm hf} \approx 100\,\mu\rm{s}$. This shows the strong sensitivity of the hyperfine coherence time on isotopic composition at low ¹²C concentrations. For a dot size of $N = 10^4$ atoms, this purification level of 99.99% would already mean that on average just one ¹³C atom would be present per dot. By selecting the dots without any ¹³C and thus no nuclear spins, one can completely lift the limitation of the coherence time by the hyperfine interaction.

Appendix B: Raman peaks fitting parameters

We fitted the Raman spectrum with Lorenzian function $\frac{A\Gamma^2}{(\omega-\omega_0)^2+\Gamma^2}$ where A is the peak amplitude, k is the

wavenumber, k_0 is the peak wavenumber, and Γ is the linewidth (half-width-half-maximum). The results are shown below. We used a single Lorenzian function for G and 2D' peaks, sum of two Lorenzian functions for D + D'' peak, and sum of three Lorenzian functions for 2D peak.

$\begin{array}{c c c c c c c c c } \mbox{Layers} & 1 & 1 & 2 & 2 \\ \hline Material & {}^{12}{\rm C} & {}^{13}{\rm C} & {}^{12}{\rm C} & {}^{13}{\rm C} \\ \hline & {}^{13}{\rm C} & {}^{12}{\rm C} & {}^{13}{\rm C} \\ \hline & {}^{13}{\rm C} & {}^{12}{\rm C} & {}^{13}{\rm C} \\ \hline & {}^{13}{\rm C} & {}^{13}{\rm C} & {}^{13}{\rm C} \\ \hline & {}^{13}{\rm C} & {}^{13}{\rm C} & {}^{13}{\rm C} \\ \hline & {}^{13}{\rm C} & {}^{13}{\rm C} & {}^{13}{\rm C} \\ \hline & {}^{13}{\rm C} & {}^{13}{\rm C} & {}^{13}{\rm C} \\ \hline & {}^{13}{\rm C} & {}^{13}{\rm C} & {}^{13}{\rm C} \\ \hline & {}^{13}{\rm C} & {}^{13}{\rm C} & {}^{1581} & {}^{1522} \\ \hline & {}^{13}{\rm C} & {}^{13}{\rm C} & {}^{1581} & {}^{1522} \\ \hline & {}^{13}{\rm G} & {}^{13}{\rm C} & {}^{2580} & {}^{2646} & {}^{2546} \\ & {}^{2646} & {}^{2580} & {}^{2646} & {}^{2580} \\ \hline & {}^{20}{\rm cm}^{-1} & {}^{2678} & {}^{2580} & {}^{2704} & {}^{2602} \\ \hline & {}^{14}{\rm L}^{29}{\rm cm}^{-1} & {}^{21.431} & {}^{22.296} & {}^{31.32} & {}^{29.96} \\ \hline & {}^{12}{\rm cm}^{-1} & {}^{21.431} & {}^{22.296} & {}^{31.32} & {}^{29.96} \\ \hline & {}^{20}{\rm cm}^{-1} & {}^{3247} & {}^{3128} & {}^{3248} & {}^{3125} \\ \hline & {}^{20}{\rm cm}^{-1} & {}^{2457} & {}^{2388} & {}^{2489} & {}^{2394} \\ \hline & {}^{41.27}{\rm cm}^{-1} & {}^{2457} & {}^{2388} & {}^{2489} & {}^{2394} \\ \hline & {}^{12}{\rm \Gamma}_{D+D''} [{\rm cm}^{-1} & {}^{15.29} & {}^{36.46} & {}^{48.69} & {}^{41.55} \\ \hline \end{array}$					
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Layers	1 -	-	-	-
$\begin{array}{c c c} \hline \Gamma_G[\mathrm{cm}^{-1}] & 8.143 & 5.316 & 11.14 & 9.983 \\ \hline & & & & 2646, & 2546, \\ & & & 2681, & 2580, \\ \hline & & & & 2681, & 2580, \\ \hline & & & & & 2681, & 2580, \\ \hline & & & & & & 2681, & 2580, \\ \hline & & & & & & & & & & & \\ \hline & & & & &$	Material	^{12}C	^{13}C	^{12}C	^{13}C
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\omega_G [\mathrm{cm}^{-1}]$	1584	1530	1581	1522
$\begin{array}{c ccccc} & & & & & & & & & & & & & & & & &$	$\Gamma_G[\mathrm{cm}^{-1}]$	8.143	5.316	11.14	9.983
$\begin{array}{c ccccc} \omega_{2D}[{\rm cm}^{-1}] & 2678 & 2580 & 2704 & 2602 \\ & & 14.98 & 13.49 \\ & & 21.76 & 21.47 \\ \Gamma_{2D}[{\rm cm}^{-1}] & 21.431 & 22.296 & 31.32 & 29.96 \\ \hline \\ \hline \\ \omega_{2D'}[{\rm cm}^{-1}] & 3247 & 3128 & 3248 & 3125 \\ \hline \\ \hline \\ \Gamma_{2D'}[{\rm cm}^{-1}] & 8.455 & 11.274 & 8.709 & 10.61 \\ \hline \\ \\ \hline \\ \\ \omega_{D+D''}[{\rm cm}^{-1}] & 2457 & 2388 & 2489 & 2394 \\ \hline \\ \hline \end{array}$				2646,	2546,
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				2681,	2580,
$\begin{array}{c ccccc} & & & & & & & & & & & & & & & & \\ \hline \Gamma_{2D}[\mathrm{cm}^{-1}] & 21.431 & 22.296 & 31.32 & 29.96 \\ \hline \omega_{2D'}[\mathrm{cm}^{-1}] & 3247 & 3128 & 3248 & 3125 \\ \hline \Gamma_{2D'}[\mathrm{cm}^{-1}] & 8.455 & 11.274 & 8.709 & 10.61 \\ \hline & & & & & & & \\ \hline \omega_{D+D''}[\mathrm{cm}^{-1}] & 2479 & 2366 & 2458 & 2365 \\ \hline & & & & & & & & \\ \hline & & & & & & & &$	$\omega_{2D} [\mathrm{cm}^{-1}]$	2678	2580	2704	2602
$\begin{array}{c ccccc} \hline \Gamma_{2D}[\text{cm}^{-1}] & 21.431 & 22.296 & 31.32 & 29.96 \\ \hline \omega_{2D'}[\text{cm}^{-1}] & 3247 & 3128 & 3248 & 3125 \\ \hline \Gamma_{2D'}[\text{cm}^{-1}] & 8.455 & 11.274 & 8.709 & 10.61 \\ \hline \omega_{D+D''}[\text{cm}^{-1}] & 2479 & 2366 & 2458 & 2365 \\ \hline \omega_{D+D''}[\text{cm}^{-1}] & 2457 & 2388 & 2489 & 2394 \\ \hline & 41.27 & 14.41 & 26.04 & 21.82 \\ \hline \end{array}$				14.98,	13.49,
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$				21.76,	21.47,
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$		21.431	22.296	31.32	29.96
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		3247	3128	3248	3125
$\frac{\omega_{D+D''}[\text{cm}^{-1}]}{41.27}, \frac{2457}{14.41}, \frac{2388}{26.04}, \frac{2394}{21.82},$	$\Gamma_{2D'}[\mathrm{cm}^{-1}]$	8.455	11.274	8.709	10.61
41.27, 14.41, 26.04, 21.82,		2479,	2366,	2458,	2365,
	$\omega_{D+D^{\prime\prime}}[\mathrm{cm}^{-1}]$	2457	2388	2489	2394
$\left \Gamma_{D+D''} [\mathrm{cm}^{-1}] \right 15.29 36.46 48.69 41.55$		41.27,	14.41,	26.04,	21.82,
	$\Gamma_{D+D''}[\mathrm{cm}^{-1}]$	15.29	36.46	48.69	41.55

TABLE I. Table of fit parameters for the Raman peaks. We fit the data with the sum of one to three Lorentzian functions (in the case we use multiple Lorenzian to fit, all fit parameters are shown in order and separated by comma).

Appendix C: Estimation of moire unit cell size from the Brown-Zak oscillation

We have estimated the moire cell size with two ap-First, since the satellite Dirac peaks approaches. pear once all the available states in the moiré cell are filled, we can determine the area A of the moiré cell from the average of the excess carrier density of the electron- and hole-side peaks $n_{ep} = 1.78 \times 10^{12} \text{ cm}^{-2}$ and $n_{hp} = -2.31 \times 10^{12} \text{ cm}^{-2}$. Considering the 4-fold degeneracy in graphene, this condition corresponds to $A = \frac{4}{\frac{1}{2}(|n_{ep}|+|n_{hp}|)}$. The second approach uses the periodicity of the Brown-Zak oscillations, which appear if a rational number 1/p of flux quanta ϕ_0 (p is an integer) passes through one moiré cell. The moiré cell area can then be determined from the positions of two adjacent Brown-Zak peaks in magnetic field $(B_1 \text{ and } B_2)$ using $A = \phi_0 \left| \frac{1}{B_1} - \frac{1}{B_2} \right|$. The lattice constant can be obtained from the area by simple geometric considerations as $L = \sqrt{2A/\sqrt{3}}$. Both methods give a consistent estimate of the moire unit cell size of 10 nm, which is reasonable for the graphene/hBN-aligned system.

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